1. A sheet manufacturing method, comprising the steps of: cooling a base having protrusions;

dipping surfaces of said protrusions of said cooled base into a melt material containing at least one of a metal material and a semiconductor material; and

forming crystals of said material on the surfaces of said protrusions.

2. A sheet manufacturing method, comprising the steps of: rotating a roller with protrusions on its peripheral surface and a cooling portion capable of cooling said protrusions;

dipping surfaces of said cooled protrusions into a melt material containing at least one of a metal material and a semiconductor material; and

forming crystals of said material on the surfaces of said protrusions.

- 3. The sheet manufacturing method according to claim 1, wherein said protrusions have at least one of dot-like protrusions and linear protrusions.
- 4. The sheet manufacturing method according to claim 2, wherein said protrusions have at least one of dot-like protrusions and linear protrusions.
- 5. The sheet manufacturing method according to claim 1, wherein said protrusions have at least one of dot-like protrusions and linear protrusions in addition to planar protrusions.
- 6. The sheet manufacturing method according to claim 2, wherein said protrusions have at least one of dot-like protrusions and linear protrusions in addition to planar protrusions.

- 7. The sheet manufacturing method according to claim 1, wherein said protrusions are coated with a coating material of at least one of silicon carbide, boron nitride, silicon nitride and pyrolitic carbon.
- 8. The sheet manufacturing method according to claim 2, wherein said protrusions are coated with a coating material of at least one of silicon carbide, boron nitride, silicon nitride and pyrolitic carbon.
- 9. The sheet manufacturing method according to claim 1, wherein crystal growth of said material starts from said protrusions.
- 10. The sheet manufacturing method according to claim 2, wherein crystal growth of said material starts from said protrusions.
- 11. A sheet produced by cooling a base having protrusions, dipping surfaces of said protrusions of said cooled base into a melt material containing at least one of a metal material and a semiconductor material, wherein said sheet has a curve portion obtained by forming crystals of said material from protrusions on the surface of said base in a curved shape.
- 12. A sheet produced by cooling a base having at least one of dot-like protrusions and linear protrusions in addition to planar protrusions and dipping surfaces of said protrusions of said cooled base into a material containing at least one of a metal material and a semiconductor material, wherein said sheet has curved portions and planar portions obtained respectively by forming crystals of said material from said dot-like protrusions or linear protrusions on the surface of said base in a curved shape and by forming crystals of said material from planar protrusions on the surface of said substrate in a planar shape.
- 13. A sheet manufacturing apparatus, comprising: a roller having on its peripheral surface protrusions and a cooling portion for cooling said protrusions; and

a crucible including a melt material containing at least one of a metal material and a semiconductor material and capable of dipping said protrusions into said melt by rotation of said roller.

- 14. A solar cell produced by forming an electrode on a sheet formed by cooling a base with protrusions and dipping the surfaces of said protrusions of said cooled base into a melt material containing at least one of a metal material and a semiconductor material, wherein said sheet has curved portions obtained by forming crystals of said material from said protrusions on the surface of said base in a curved shape.
- by cooling a base with at least one of dot-like protrusions and linear protrusions in addition to planar protrusions and dipping a surface of said cooled base into a melt material containing at least one of a metal material and a semiconductor material, wherein said sheet has curved portions and planar portions obtained respectively by forming crystals of said material from said dot-like protrusions or linear protrusions on the surface of said base in a curved shape and by forming said crystals of said material from said planar protrusions on the surface of said base in a planar shape.
- 16. The silicon sheet manufacturing apparatus of manufacturing a silicon sheet by solidifying a silicon melt by rotation of a cooling roller for crystal growth, characterized in that said cooling roller has in its surface protrusions arranged in a dot-like pattern or in a linear pattern when viewed from above.
- 17. The silicon sheet manufacturing apparatus according to claim 16, characterized in that a space between said protrusions is in a V or U like shape.
- 18. The silicon sheet manufacturing apparatus according to claim 16, characterized in that the surface of said cooling roller is covered with an

SiC film.

- 19. The silicon sheet manufacturing apparatus according to claim 17, characterized in that a pitch of said V or U grooves is at least 0.05mm and at most 5mm.
- 20. The silicon sheet manufacturing apparatus according to claim 16, wherein a height of said protrusions is at least 0.05mm and at most 5mm.
- 21. A silicon sheet manufacturing method of manufacturing a silicon sheet by solidifying a silicon melt by rotation of a cooling roller for crystal growth, characterized in that said crystals grow from protrusions of said cooling roller arranged in a dot-like pattern or in a linear pattern when viewed from above.
- 22. A solar cell produced by rotating a roller having on its peripheral surface protrusions having at least one of dot-like protrusions and linear protrusions and a cooling portion for cooling said protrusions, and dipping surfaces of said cooled protrusions into a silicon melt so that silicon crystals grow on the surfaces of said protrusions.